

BL GALAXY ELECTRICAL

BYW96D(Z)---BYW96E(Z)

FAST RECOVERY RECTIFIERS

VOLTAGE RANGE: 800 --- 1000 V
CURRENT: 3.0 A

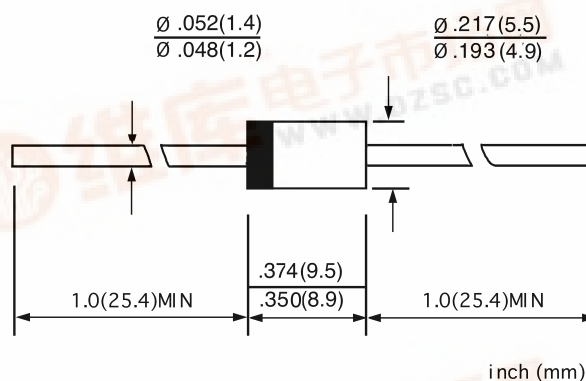
FEATURES

- ◇ Low cost
- ◇ Diffused junction
- ◇ Low leakage
- ◇ Low forward voltage drop
- ◇ High current capability
- ◇ Easily cleaned with Freon Alcohol, Isopropanol and similar solvents

MECHANICAL DATA

- ◇ Case: JEDEC DO--27, molded plastic
- ◇ Terminals: Axial lead, solderable per MIL-STD-202, Method 208
- ◇ Polarity: Color band denotes cathode
- ◇ Weight: 0.041 ounces, 1.15 grams
- ◇ Mounting position: Any

DO - 27



MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 50Hz, resistive or inductive load. For capacitive load, derate by 20%.

		BYW96D	BYW96E	UNITS
Maximum recurrent peak reverse voltage	V_{RRM}	800	1000	V
Maximum RMS voltage	V_{RMS}	560	700	V
Maximum DC blocking voltage	V_{DC}	800	1000	V
Maximum average forward rectified current 9.5mm lead length, @ $T_A=75^\circ\text{C}$	$I_{F(AV)}$	3.0		A
Peak forward surge current 10ms single half-sine-wave superimposed on rated load @ $T_J=125^\circ\text{C}$	I_{FSM}	70.0		A
Maximum instantaneous forward voltage @ 3.0 A	V_F	1.5		V
Maximum reverse current @ $T_A=25^\circ\text{C}$ at rated DC blocking voltage @ $T_A=100^\circ\text{C}$	I_R	10.0 100.0		μA
Maximum reverse recovery time (Note1)	t_{rr}	300		ns
Typical junction capacitance (Note2)	C_J	32		pF
Typical thermal resistance (Note3)	$R_{\theta JA}$	22		$^\circ\text{C/W}$
Operating junction temperature range	T_J	-55-----+150		$^\circ\text{C}$
Storage temperature range	T_{STG}	-55-----+150		$^\circ\text{C}$

NOTE:1. Measured with $I_F=0.5\text{A}$, $I_R=1\text{A}$, $I_{rr}=0.25\text{A}$.

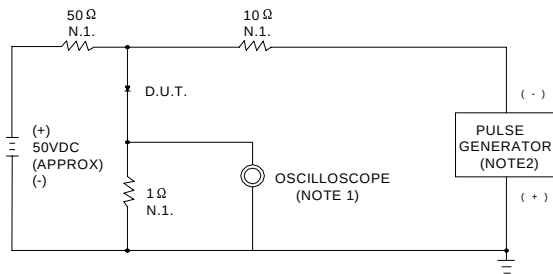
2. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.

3. Thermal resistance from junction to ambient.

RATINGS AND CHARACTERISTIC CURVES

BYW96D(Z)---BYW96E(Z)

FIG.1 – REVERSE RECOVERY TIME CHARACTERISTIC AND TEST CIRCUIT DIAGRAM



NOTES: 1. RISE TIME = 7ns MAX. INPUT IMPEDANCE = 1MΩ, 22pF
2. RISE TIME = 10ns MAX. SOURCE IMPEDANCE = 50Ω

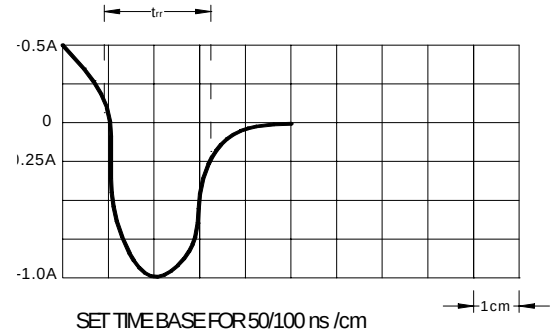


FIG.2 – FORWARD DERATING CURVE

AVERAGE FORWARD RECTIFIED CURRENT
AMPERES

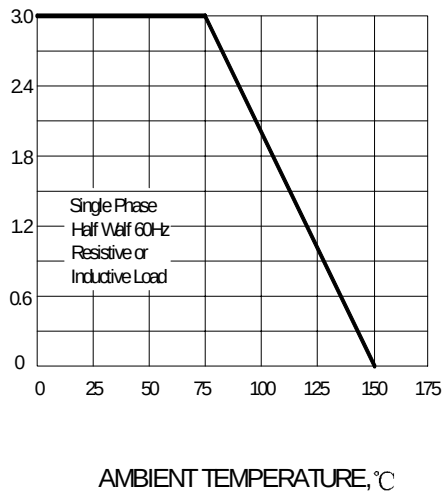


FIG.3 – PEAK FORWARD SURGE CURRENT

PEAK FORWARD SURGE CURRENT
AMPERES

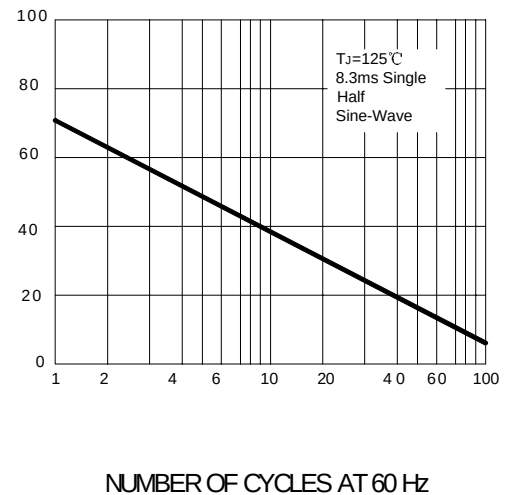


FIG.4 – TYPICAL FORWARD CHARACTERISTIC

INSTANTANEOUS REVERSE CURRENT
AMPERES

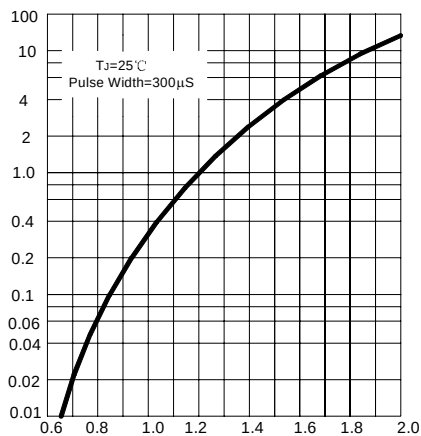


FIG.5 – TYPICAL JUNCTION CAPACITANCE

JUNCTION CAPACITANCE, pF

